



GlobalOptoisolatorTM



Solid State Relays

Motor Controls

Τд

Tstg

ΤL

-40 to +85

-40 to +150

260

°C °C

°C

Temperature Controls

Incandescent Lamp Dimmers

6-Pin DIP Random-Phase **Optoisolators Triac Drivers** (600 Volts Peak)

The MOC3051 Series consists of a GaAs infrared LED optically coupled to a non-Zero-crossing silicon bilateral AC switch (triac). The MOC3051 Series isolates low voltage logic from 115 and 240 Vac lines to provide random phase control of high current triacs or thyristors. The MOC3051 Series features greatly enhanced static dv/dt capability to ensure stable switching performance of inductive loads.

To order devices that are tested and marked per VDE 0884 requirements, the • suffix "V" must be included at end of part number. VDE 0884 is a test option.

Recommended for 115/240 Vac(rms) Applications:

- Solenoid/Valve Controls .
- Lamp Ballasts
- Static AC Power Switch
- Interfacing Microprocessors to 115 and 240 Vac Peripherals

Ambient Operating Temperature Range

Storage Temperature Range

Soldering Temperature (10 s)

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
INFRARED EMITTING DIODE			
Reverse Voltage	VR	3	Volts
Forward Current — Continuous	١ _F	60	mA
Total Power Dissipation @ T _A = 25°C Negligible Power in Triac Driver	PD	100	mW
		1.33	mvv/°C
OUTPUT DRIVER		-	
Off-State Output Terminal Voltage	VDRM	600	Volts
Peak Repetitive Surge Current (PW = 100 μs, 120 pps)	ITSM	1	A
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	300 4	mW mW/°C
TOTAL DEVICE			
Isolation Surge Voltage (1) (Peak ac Voltage, 60 Hz, 1 Second Duration)	VISO	7500	Vac(pk)
Total Power Dissipation @ T _A = 25°C Derate above 25°C	PD	330 4.4	mW mW/°C
Junction Temperature Range	T.I	-40 to +100	°C

MOC3051 MOC3052



COUPLER SCHEMATIC 1 **П**6 3 -04 1. ANODE 2. CATHODE 3. NC 4. MAIN TERMINAL 5. SUBSTRATE DO NOT CONNECT 6. MAIN TERMINAL



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit		
INPUT LED							
Reverse Leakage Current (V _R = 3 V)	IR	—	0.05	100	μA		
Forward Voltage (I _F = 10 mA)	۷F	_	1.15	1.5	Volts		
OUTPUT DETECTOR (I _F = 0 unless otherwise noted)							
Peak Blocking Current, Either Direction (Rated V _{DRM} , Note 1) @ I _{FT} per device	IDRM	_	10	100	nA		
Peak On–State Voltage, Either Direction (I _{TM} = 100 mA Peak)	VTM	—	1.7	2.5	Volts		
Critical Rate of Rise of Off-State Voltage @ 400 V (Refer to test circuit, Figure 10)	dv/dt static	1000	—	—	V/µs		
COUPLED							
LED Trigger Current, Either Direction, Current Required to Latch Output (Main Terminal Voltage = 3 V, Note 2) MOC3051 MOC3052	IFT		_	15 10	mA		
Holding Current, Either Direction	ŀн	—	280	_	μA		

1. Test voltage must be applied within dv/dt rating.

2. All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT}. Therefore, recommended operating I_F lies between max 15 mA for MOC3051, 10 mA for 3052 and absolute max I_F (60 mA).





TYPICAL ELECTRICAL CHARACTERISTICS

T_A = 25°C



Figure 2. On–State Characteristics



TYPICAL ELECTRICAL CHARACTERISTICS

T_A = 25°C



Figure 3. Trigger Current versus Temperature



Figure 4. LED Current Required to Trigger versus LED Pulse Width



Figure 5. Minimum Time for LED Turn–Off to Zero Cross of AC Trailing Edge

IFT versus Temperature (normalized)

This graph shows the increase of the trigger current when the device is expected to operate at an ambient temperature below 25° C. Multiply the normalized I_{FT} shown on this graph with the data sheet guaranteed I_{FT}.

Example:

 $T_A = -40^{\circ}C$, $I_{FT} = 10 \text{ mA}$ $I_{FT} @ -40^{\circ}C = 10 \text{ mA x } 1.4 = 14 \text{ mA}$

Phase Control Considerations

LED Trigger Current versus PW (normalized)

Random Phase Triac drivers are designed to be phase controllable. They may be triggered at any phase angle within the AC sine wave. Phase control may be accomplished by an AC line zero cross detector and a variable pulse delay generator which is synchronized to the zero cross detector. The same task can be accomplished by a microprocessor which is synchronized to the AC zero crossing. The phase controlled trigger current may be a very short pulse which saves energy delivered to the input LED. LED trigger pulse currents shorter than 100 μ s must have an increased amplitude as shown on Figure 4. This graph shows the dependency of the trigger current IFT versus the pulse width t (PW). The reason for the IFT dependency on the pulse width can be seen on the chart delay t(d) versus the LED trigger current.

IFT in the graph IFT versus (PW) is normalized in respect to the minimum specified IFT for static condition, which is specified in the device characteristic. The normalized IFT has to be multiplied with the devices guaranteed static trigger current.

Example:

Guaranteed I_{FT} = 10 mA, Trigger pulse width PW = $3 \mu s$ I_{FT} (pulsed) = 10 mA x 5 = 50 mA

Minimum LED Off Time in Phase Control Applications

In Phase control applications one intends to be able to control each AC sine half wave from 0 to 180 degrees. Turn on at zero degrees means full power and turn on at 180 degree means zero power. This is not quite possible in reality because triac driver and triac have a fixed turn on time when activated at zero degrees. At a phase control angle close to 180 degrees the driver's turn on pulse at the trailing edge of the AC sine wave must be limited to end 200 μ s before AC zero cross as shown in Figure 5. This assures that the triac driver has time to switch off. Shorter times may cause loss of control at the following half cycle.



TYPICAL ELECTRICAL CHARACTERISTICS

T_A = 25°C



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Figure 8. ED Trigger Current, IFT, versus dv/dt



Figure 7. Leakage Current, IDRM versus Temperature

IFT versus dv/dt

Triac drivers with good noise immunity (dv/dt static) have internal noise rejection circuits which prevent false triggering of the device in the event of fast raising line voltage transients. Inductive loads generate a commutating dv/dt that may activate the triac drivers noise suppression circuits. This prevents the device from turning on at its specified trigger current. It will in this case go into the mode of "half waving" of the load. Half waving of the load may destroy the power triac and the load.

Figure 8 shows the dependency of the triac drivers IFT versus the reapplied voltage rise with a Vp of 400 V. This dv/dt condition simulates a worst case commutating dv/dt amplitude.

It can be seen that the IFT does not change until a commutating dv/dt reaches 1000 V/ μ s. Practical loads generate a commutating dv/dt of less than 50 V/ μ s. The data sheet specified IFT is therefore applicable for all practical inductive loads and load factors.





T₄ = 25°C



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t(delay), t(f) versus IFT

The triac driver's turn on switching speed consists of a turn on delay time t(d) and a fall time t(f). Figure 9 shows that the delay time depends on the LED trigger current, while the actual trigger transition time t(f) stays constant with about one micro second.

The delay time is important in very short pulsed operation because it demands a higher trigger current at very short trigger pulses. This dependency is shown in the graph IFT versus LED PW.

The turn on transition time t(f) combined with the power triac's turn on time is important to the power dissipation of this device.

Switching Time Test Circuit





- 1. The mercury wetted relay provides a high speed repeated pulse to the D.U.T.
- 2. 100x scope probes are used, to allow high speeds and voltages.
- 3. The worst-case condition for static dv/dt is established by triggering the D.U.T. with a normal LED input current, then removing the current. The variable $\mathsf{R}_{\ensuremath{\mathsf{TEST}}}$ allows the dv/dt to be gradually increased until the D.U.T. continues to trigger in response to the applied voltage pulse, even after the LED current has been removed. The dv/dt is then decreased until the D.U.T. stops triggering. τ_{RC} is measured at this point and recorded.

Figure 10. Static dv/dt Test Circuit

TRC



APPLICATIONS GUIDE

Basic Triac Driver Circuit

The new random phase triac driver family MOC3052 and MOC3051 are very immune to static dv/dt which allows snubberless operations in all applications where external generated noise in the AC line is below its guaranteed dv/dt withstand capability. For these applications a snubber circuit is not necessary when a noise insensitive power triac is used. Figure 11 shows the circuit diagram. The triac driver is directly connected to the triac main terminal 2 and a series Resistor R which limits the current to the triac driver. Current limiting resistor R must have a minimum value which restricts the current into the driver to maximum 1A.

R = Vp AC/ITM max rep. = Vp AC/1A

The power dissipation of this current limiting resistor and the triac driver is very small because the power triac carries the load current as soon as the current through driver and current limiting resistor reaches the trigger current of the power triac. The switching transition times for the driver is only one micro second and for power triacs typical four micro seconds.

Triac Driver Circuit for Noisy Environments

When the transient rate of rise and amplitude are expected to exceed the power triacs and triac drivers maximum ratings a snubber circuit as shown in Figure 12 is recommended. Fast transients are slowed by the R–C snubber and excessive amplitudes are clipped by the Metal Oxide Varistor MOV.









Triac Driver Circuit for Extremely Noisy Environments,

as specified in the noise standards IEEE472 and IEC255–4. Industrial control applications do specify a maximum transient noise dv/dt and peak voltage which is superimposed onto the AC line voltage. In order to pass this environment noise test a modified snubber network as shown in Figure 13 is recommended.



Recommended snubber to pass IEEE472 and IEC255–4 noise tests $R_S = 47$ W, $C_S = 0.01$ mF

Figure 13. Triac Driver Circuit for Extremely Noisy Environments



MOC3051, MOC3052

PACKAGE DIMENSIONS









MOC3051, MOC3052



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